

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





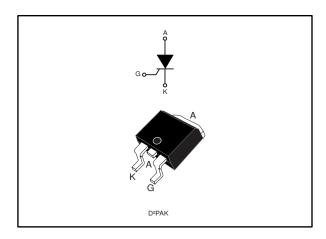


## TN4015H-6G



## High temperature 40 A SCRs

Datasheet - production data



#### **Features**

- High junction temperature : T<sub>i</sub> = 150 °C
- High noise immunity  $dV/dt = 500 V/\mu s$  up to 150 °C
- Gate triggering current I<sub>GT</sub> = 15 mA
- Off-sate voltage 600 V VDRM/VRRM
- High turn on current rise dl/dt = 100 A/μs
- ECOPACK®2 compliant component

## **Applications**

- · Motorbike voltage regulator circuits
- Inrush current limiting circuit
- Motor control circuits and starters
- Solid state relays

### **Description**

Thanks to its junction temperature T<sub>j</sub> up to 150 °C, the device offers high thermal performances operation up to 40 A. Its D2PAK package allows modern SMD designs as well as compact back to back configuration.

Its trade-off noise immunity (dV/dt = 500 V/ $\mu$ s) versus its gate triggering current (I<sub>GT</sub> = 15 mA) and its turn-on current rise (dI/dt = 100 A/ $\mu$ s) allows to design robust and compact control circuit for voltage regulator in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits.

**Table 1: Device summary** 

Order code	Package	V <sub>DRM</sub> /V <sub>RRM</sub>	Ідт
TN4015H-6G	D <sup>2</sup> PAK	600 V	15 mA

Characteristics TN4015H-6G

### 1 Characteristics

Table 2: Absolute maximum ratings (limiting values), T<sub>j</sub> = 25 °C unless otherwise specified

Symbol	Parameter	Value	Unit		
I <sub>T(RMS)</sub>	RMS on-state current (180 ° conduction	T <sub>c</sub> = 119 °C	40	Α	
			T <sub>c</sub> = 120 °C	25	
$I_{T(AV)}$	Average on-state current (180 ° conducti	T <sub>c</sub> = 125 °C	22	Α	
			T <sub>c</sub> = 128 °C	20	
I <sub>TSM</sub>	Non repetitive gurge peak on state gurre	nt	$t_p = 8.3 \text{ ms}$	394	Α
IISM	Non repetitive surge peak on-state curre	IIL	$t_p = 10 \text{ ms}$	360	A
l <sup>2</sup> t	I <sup>2</sup> t value for fusing		$t_p = 10 \text{ ms}$	648	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$	f = 60 Hz	100	A/μs	
V <sub>DRM</sub> /V <sub>RRM</sub>	Repetitive peak off-state voltage	T <sub>j</sub> = 150 °C	600	V	
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltaç	t <sub>p</sub> = 10 ms	V <sub>DRM</sub> /V <sub>RRM</sub> + 100	V	
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 150 °C	4	Α
P <sub>G(AV)</sub>	Average gate power dissipation	T <sub>j</sub> = 150 °C	1	W	
$V_{RGM}$	Maximum peak reverse gate voltage	5	V		
T <sub>stg</sub>	Storage junction temperature range	-40 to +150	°C		
Tj	Maximum operating junction temperature	-40 to +150	°C		
TL	Maximum lead temperature soldering du		260	°C	

Table 3: Electrical characteristics ( $T_j = 25$  °C unless otherwise specified)

Symbol	Test Conditions		Value	Unit	
lgт	V 40 V D = 22 O		Max.	15	mA
$V_{GT}$	$V_D = 12 \text{ V}, \text{ R}_L = 33 \Omega$		Max.	1.3	V
$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		Min.	0.15	V
Ін	I <sub>T</sub> = 500 mA, gate open		Max.	60	mA
IL	$I_G = 1.2 \text{ x } I_{GT}$		Max.	80	mA
dV/dt	$V_D = 402 \text{ V}$ , gate open $T_j = 150 \text{ °C}$		Min.	500	V/µs
t <sub>gt</sub>	$I_T = 80 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A/}\mu\text{s}$			1.9	μs
tq	$V_D = 402 \text{ V}, \ I_T = 40 \text{ A}, \ V_R = 25 \text{ V}, \ dV_D/dt = 50 \text{ V}/\mu s, \ (dI_G/dt)max = 30 \text{ A}/\mu s$ $T_j = 150 \text{ °C}$		Тур.	85	μs

TN4015H-6G Characteristics

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit	
V <sub>TM</sub>	$I_{TM} = 80 \text{ A}, t_p = 380 \mu s$	T <sub>j</sub> = 25 °C	Max.	1.6	٧	
$V_{TO}$	Threshold voltage	T <sub>j</sub> = 150 °C	Max.	0.85	V	
R <sub>D</sub>	Dynamic resistance	T <sub>j</sub> = 150 °C	Max.	10	mΩ	
I <sub>DRM</sub> ,	V V V	T <sub>j</sub> = 25 °C	Max	10	μΑ	
I <sub>RRM</sub>	$V_D = V_{DRM} = V_{RRM}$	T <sub>j</sub> = 150 °C	Max.	6	mA	

**Table 5: Thermal parameters** 

Symbol	Parameter				Unit
R <sub>th(j-c)</sub>	Junction to case (DC)		Max.	8.0	0C/M
R <sub>th(j-a)</sub>	Junction to ambient (DC)	$S^{(1)} = 1 \text{ cm}^2$	Тур.	45	°C/W

#### Notes:

 $^{(1)}S$  = Copper surface under tab

Characteristics TN4015H-6G

### 1.1 Characteristics (curves)

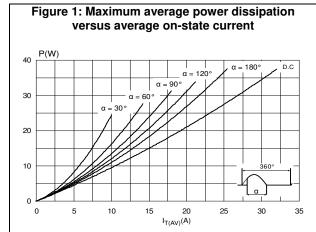


Figure 3: Average and D.C. on state current versus ambient temperature  $I_{T(AV)}(A)$ 3.0 2.5 20 a = 1801.5 1.0 0.5 0.0 0 25 50 75 100 125 150 T<sub>a</sub>(°C)

Figure 4: Relative variation of thermal impedance versus pulse duration

1.0E+00

K = [Z<sub>th</sub>/R<sub>th</sub>]

1.0E-01

1.0E-03

1.0E-03

1.0E-03

1.0E-02

1.0E-03

1.0E-03

1.0E-03

1.0E-03

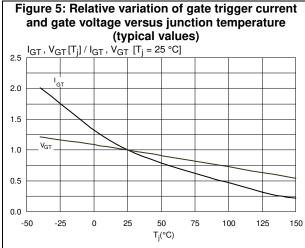
1.0E-03

1.0E-03

1.0E-03

1.0E-03

1.0E-03



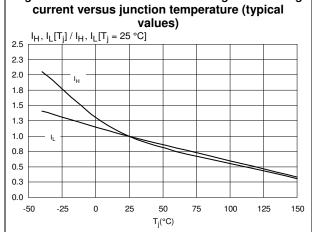
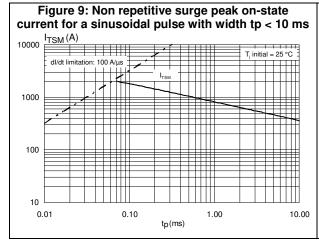


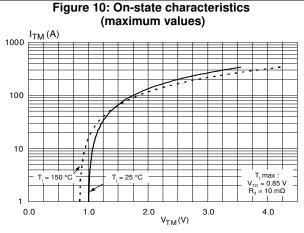
Figure 6: Relative variation of holding and latching

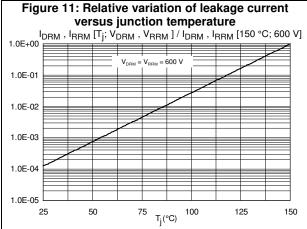
TN4015H-6G Characteristics

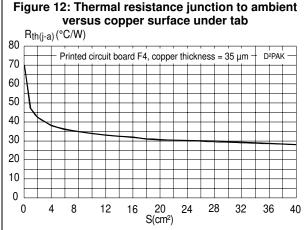
Figure 7: Relative variation of static dV/dt immunity versus junction temperature (typical values) dV/dt [  $T_j$  ] / dV/dt [  $T_j$  = 150 °C ] V<sub>D</sub> = 402 V Above test equipment capability 120 125 140 145 150 110 115 T<sub>i</sub>(°C)

Figure 8: Surge peak on-state current versus number of cycles Number of cycles









## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free, halogen-free package

### 2.1 D<sup>2</sup>PAK package information

Figure 13: D<sup>2</sup>PAK package outline

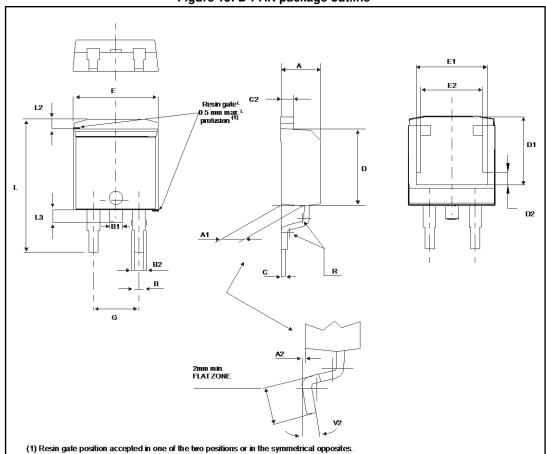
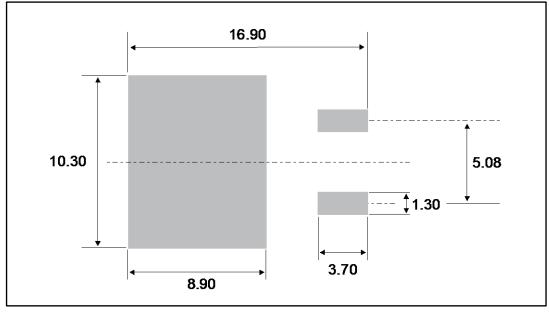


Table 6: D<sup>2</sup>PAK package mechanical data

	Dimensions					
Ref.		Millimeters				
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.30		4.60	0.1692		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0011		0.0090
В	0.70		0.93	0.0275		0.0366
B2	1.25	1.40		0.0492	0.0551	
С	0.45		0.60	0.0177		0.0236
C2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3523		0.3681
D2	1.3		1.7	0.051		0.066
Е	10.00		10.28	0.3937		0.4047
E1	8.3		8.7	0.326		0.342
E2	6.85		7.25	0.2696		0.2854
G	4.88		5.28	0.1921		0.2078
L	15.00		15.85	0.5905		0.6240
L2	1.27		1.40	0.050		0.0551
L3	1.40		1.75	0.0551		0.0688
R		0.40			0.0157	
V2	0°		8°	0°		8°

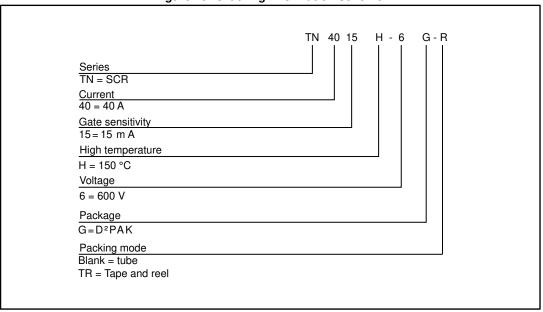
Figure 14: D<sup>2</sup>PAK recommended footprint (dimensions in mm)



Ordering information TN4015H-6G

# 3 Ordering information

Figure 15: Ordering information scheme



**Table 7: Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN4015H-6G	TN4015H6	D <sup>2</sup> PAK	1.5 g	50	Tube
TN4015H-6G-TR	TN4015H6	D <sup>2</sup> PAK	1.5 g	1000	Tape and reel

# 4 Revision history

**Table 8: Document revision history** 

Date	Revision	Changes
01-Aug-2016	1	Initial release.

#### **IMPORTANT NOTICE - PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2016 STMicroelectronics - All rights reserved

